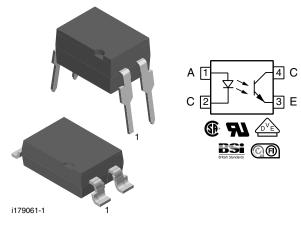




Vishay Semiconductors

Optocoupler, Phototransistor Output, Low Input Current



DESCRIPTION

The SFH618A (DIP) and SFH6186 (SMD) feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 or SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits. The couplers are end-stackable with 2.54 mm lead spacing. Creepage and clearance distances of > 8 mm achieved with option 6.

FEATURES

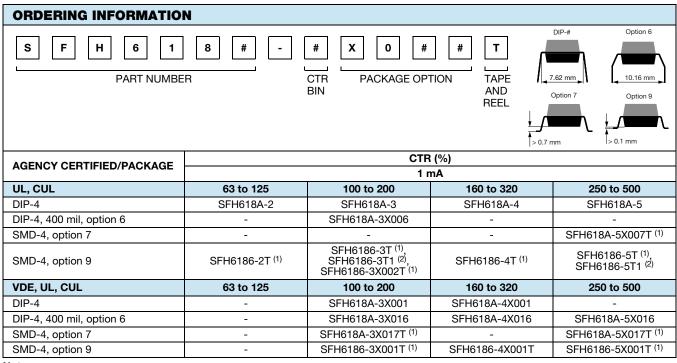
- · Good CTR linearity depending on forward current
- Low CTR degradation
- High collector emitter voltage, V_{CEO} = 55 V
- Isolation test voltage, 5300 V_{BMS}
- · Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode transient immunity
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Telecom
- Industrial controls
- Battery powered equipment
- Office machines

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- CSA 93751
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- BSI IEC 60950; IEC 60065
- FIMKO



Notes

Additional options may be possible, please contact sales office

(1)Also available in tubes, do not put T to the end

(2) Product is rotated 180° in tape and reel cavity

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1 For technical questions, contact: <u>optocoupleranswers@vishay.com</u> Document Number: 83673

RoHS

COMPLIANT



SFH618A, SFH6186

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ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25 \degree C$, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT	· · ·		·				
Reverse voltage		V _R	6	V			
Power dissipation		P _{diss}	70	mW			
Forward current		I _F	60	mA			
OUTPUT							
Collector emitter voltage		V _{CEO}	55	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		Ι _C	50	mA			
	t _p ≤ 1 ms	Ι _C	100	mA			
Power dissipation		P _{diss}	150	mW			
COUPLER							
Isolation test voltage between emitter and detector	t = 1 s	V _{ISO}	5300	V _{RMS}			
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 25 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹²	Ω			
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹¹	Ω			
Storage temperature range		T _{stg}	- 55 to + 150	°C			
Ambient temperature range		T _{amb}	- 55 to + 100	°C			
Junction temperature		Тj	125	°C			
Soldering temperature ⁽¹⁾	max. 10 s, dip soldering distance to seating plane \ge 1.5 mm	T _{sld}	260	°C			

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

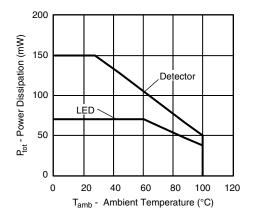


Fig. 1 - Permissible Power Dissipation vs. Ambient Temperature

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SFH618A, SFH6186

Vishay Semiconductors

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT	•	•			•		•
Forward voltage	I _F = 5 mA		V _F		1.1	1.5	V
Reverse current	V _R = 6 V		I _R		0.01	10	μA
Capacitance	V _R = 0 V, f = 1 MHz		Co		25		pF
Thermal resistance			R _{thja}		1070		K/W
OUTPUT	•	•			•		•
Collector emitter leakage current	V _{CE} = 10 V		I _{CEO}		10	200	nA
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz		C _{CE}		7		pF
Thermal resistance			R _{thja}		500		K/W
COUPLER							
Collector emitter saturation voltage	I _C = 0.32 mA, I _F = 1 mA	SFH618A-2	V _{CEsat}		0.25	0.4	V
		SFH6186-2	V _{CEsat}		0.25	0.4	V
	I _C = 0.5 mA, I _F = 1 mA	SFH618A-3	V _{CEsat}		0.25	0.4	V
		SFH6186-3	V _{CEsat}		0.25	0.4	V
		SFH618A-4	V _{CEsat}		0.25	0.4	V
	l _C = 0.8 mA, l _F = 1 mA	SFH6186-4	V _{CEsat}		0.25	0.4	V
		SFH618A-5	V _{CEsat}		0.25	0.4	V
	l _C = 1.25 mA, l _F = 1 mA	SFH6186-5	V _{CEsat}		0.25	0.4	V
Coupling capacitance			Cc		0.25		pF

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		SFH618A-2	CTR	63		125	%
	I _F = 1 mA, V _{CE} = 0.5 V	SFH6186-2	CTR	63		125	%
		SFH618A-2	CTR	32	75		%
	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$	SFH6186-2	CTR	32	75	125 125 5 200 200 200 200 200 200 320 320 320	%
		SFH618A-3	CTR	100		200	%
	I _F = 1 mA, V _{CE} = 0.5 V	SFH6186-3	CTR	100		200	%
	$I = 0.5 \text{ m} \Lambda V = 1.5 V$	SFH618A-3	CTR	50	120		%
	l _F = 0.5 mA, V _{CE} = 1.5 V	SFH6186-3	CTR	50	120		%
I _C /I _F	I _F = 1 mA, V _{CF} = 0.5 V	SFH618A-4	CTR	160		320	%
	$V_{\rm F} = 1$ mA, $V_{\rm CE} = 0.5$ V	SFH6186-4	CTR	160		320	%
		SFH618A-4	CTR	80	200		%
	$I_F = 0.5 \text{ mA}, V_{CE} = 1.5 \text{ V}$	SFH6186-4	CTR	80	200		%
	$1 - 1 m \Lambda V = 0 E V$	SFH618A-5	CTR	250		500	%
	I _F = 1 mA, V _{CE} = 0.5 V	SFH6186-5	CTR	250		500	%
	$I = 0.5 \text{ m} \Lambda V = 1.5 V$	SFH618A-5	CTR	125	300		%
	I _F = 0.5 mA, V _{CE} = 1.5 V	SFH6186-5	CTR	125	300		%

SWITCHING CHARACTERISTICS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Turn on time	V_{CC} = 5 V, I_C = 2 mA, R_L = 100 Ω	t _{on}		6		μs	
Rise time	V_{CC} = 5 V, I_C = 2 mA, R_L = 100 Ω	t _r		3.5		μs	
Turn off time	V_{CC} = 5 V, I_C = 2 mA, R_L = 100 Ω	t _{off}		5.5		μs	
Fall time	V_{CC} = 5 V, I_C = 2 mA, R_L = 100 Ω	t _f		5		μs	

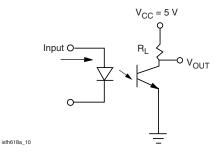
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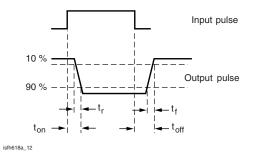


Fig. 2 - Test Circuit

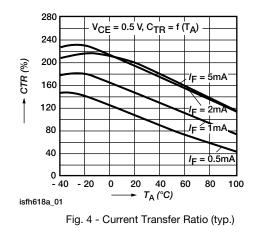


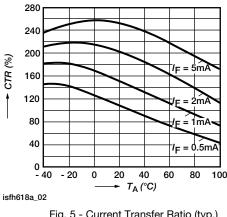
SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification (according to IEC68 part 1)				55/100/21			
Comparative tracking index		CTI	175		399		
V _{IOTM}			10000			V	
V _{IORM}			890			V	
P _{SO}					400	mW	
I _{SI}					275	mA	
T _{SI}					175	°C	
Creepage distance	Standard DIP-4		7			mm	
Clearance distance	Standard DIP-4		7			mm	
Creepage distance	400 mil DIP-4		8			mm	
Clearance distance	400 mil DIP-4		8			mm	
Insulation thickness, reinforced rated	per IEC60950 2.10.5.1		0.4			mm	

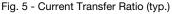
Note

As per IEC60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with ٠ the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)







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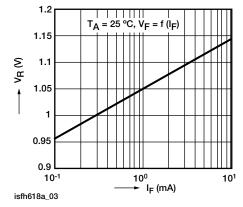


Fig. 6 - Diode Forward Voltage (typ.)

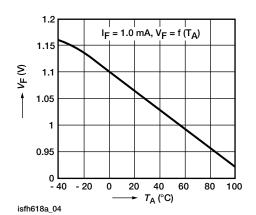


Fig. 7 - Diode Forward Voltage (typ.)

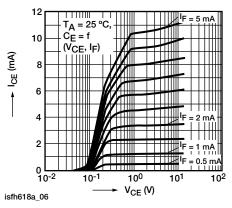


Fig. 9 - Output Characteristics

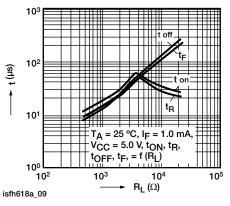


Fig. 10 - Switching Times (typ.)

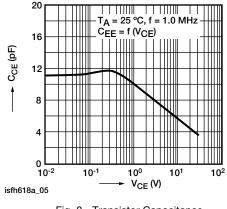


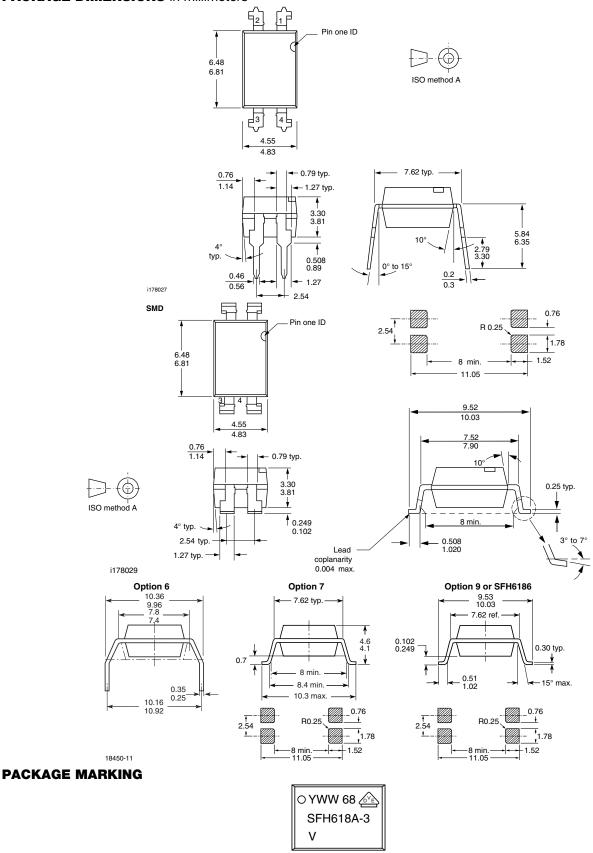
Fig. 8 - Transistor Capacitance



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PACKAGE DIMENSIONS in millimeters



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